MAX2740ECM Rev. A

RELIABILITY REPORT

FOR

MAX2740ECM

PLASTIC ENCAPSULATED DEVICES

April 29, 2003

MAXIM INTEGRATED PRODUCTS

120 SAN GABRIEL DR.

SUNNYVALE, CA 94086

Written by

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Jim Pedicord Quality Assurance Reliability Lab Manager

Reviewed by

Bryan J. Preeshl Quality Assurance Executive Director

Conclusion

The MAX2740 successfully meets the quality and reliability standards required of all Maxim products. In addition, Maxim's continuous reliability monitoring program ensures that all outgoing product will continue to meet Maxim's quality and reliability standards.

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I. Device Description

A. General

The MAX2740 is a complete global positioning system (GPS) receiver from antenna output to digitizer input. The signal path includes the LNA, two downconverters, and variable-gain and fixed-gain amplifiers. By utilizing a double-conversion superheterodyne architecture with external surface acoustic wave (SAW) filters, high levels of image rejection and blocking immunity are possible. Receiver linearity has been maximized to improve operation in hostile RFI environments found in cellular base stations. The MAX2740 also includes a high-performance voltage-controlled oscillator (VCO) with low phase noise for subcentimeter carrier phase applications, and a fixed-frequency synthesizer for generation of all required on-chip local oscillators.

The unique frequency plan captured in the MAX2740 is suitable for joint GPS/GLONASS receivers with minimal external components. This allows the MAX2740 to provide a cost-effective and high-performance solution for navigation and timing products that need maximum satellite availability.

The MAX2740 is compatible with a high-performance DSP engine capable of very fast time to first fix and excellent multipath rejection.

B. Absolute Maximum Ratings	
<u>ltem</u>	<u>Rating</u>
VCC Pins to GND	-0.3V to +4.3V
RF LNA Input Power	+10dBm
LO Input Power	+10dBm
GC Input Voltage	-0.3 to (VCC + 0.3V)
Operating Temperature Range	-40°C to +85°C
Junction Temperature	+150°C
Storage Temperature Range	-65°C to +160°C
Lead Temperature (soldering, 10s)	+300°C
Continuous Power Dissipation (TA = +70°C)	
48-Pin TQFP-EP	2432mW
Derate above +70°C	
48-Pin TQFP-EP	30.4mW/°C

II. Manufacturing Information

A. Description/Function:	Integrated GPS Receiver and Synthesizer
B. Process:	GST2 – High Speed Double Poly-Silicon Bipolar Process
C. Number of Device Transistors:	1198
D. Fabrication Location:	Oregon, USA
E. Assembly Location:	Korea
F. Date of Initial Production:	April, 2000

III. Packaging Information

A. Package Type:	48-Pin TQFP-EP
B. Lead Frame:	Copper
C. Lead Finish:	Solder Plate
D. Die Attach:	Silver-filled Epoxy
E. Bondwire:	Gold (1.2 mil dia.)
F. Mold Material:	Epoxy with silica filler
G. Assembly Diagram:	# 05-7001-0441
H. Flammability Rating:	Class UL94-V0
I. Classification of Moisture Sensitivity per JEDEC standard JESD22-112:	Level 3

IV. Die Information

A. Dimensions:	70 x 75 mils
B. Passivation:	Si_3N_4 (Silicon nitride)
C. Interconnect:	Poly / Au
D. Backside Metallization:	None
E. Minimum Metal Width:	2 microns (as drawn)
F. Minimum Metal Spacing:	2 microns (as drawn)
G. Bondpad Dimensions:	5 mil. Sq.
H. Isolation Dielectric:	SiO ₂
I. Die Separation Method:	Wafer Saw

V. Quality Assurance Information

Α.	Quality Assurance Contacts:	Jim Pedicord (Reliability Lab Manager)
		Bryan Preeshl (Executive Director)
		Kenneth Huening (Vice President)

- B. Outgoing Inspection Level: 0.1% for all electrical parameters guaranteed by the Datasheet.
 0.1% For all Visual Defects.
- C. Observed Outgoing Defect Rate: < 50 ppm
- D. Sampling Plan: Mil-Std-105D

VI. Reliability Evaluation

A. Accelerated Life Test

The results of the 150°C biased (static) life test are shown in **Table 1**. Using these results, the Failure Rate (λ) is calculated as follows:

 $\lambda = \underbrace{1}_{\text{MTTF}} = \underbrace{\frac{1.83}{192 \times 9823 \times 45 \times 2}}_{\text{Temperature Acceleration factor assuming an activation energy of 0.8eV}$

λ = 10.78 x 10⁻⁹

 λ = 10.78 F.I.T. (60% confidence level @ 25°C)

This low failure rate represents data collected from Maxim's reliability monitor program. In addition to routine production Burn-In, Maxim pulls a sample from every fabrication process three times per week and subjects it to an extended Burn-In prior to shipment to ensure its reliability. The reliability control level for each lot to be shipped as standard product is 59 F.I.T. at a 60% confidence level, which equates to 3 failures in an 80 piece sample. Maxim performs failure analysis on any lot that exceeds this reliability control level. Maxim also performs quarterly 1000 hour life test monitors. This data is published in the Product Reliability Report (**RR-B3A**).

B. Moisture Resistance Tests

Maxim pulls pressure pot samples from every assembly process three times per week. Each lot sample must meet an LTPD = 20 or less before shipment as standard product. Additionally, the industry standard 85°C/85%RH testing is done per generic device/package family once a quarter.

C. E.S.D. and Latch-Up Testing

The WG01 die type has been found to have all pins able to withstand a transient pulse of ± 250 V, per Mil-Std-883 Method 3015 (reference attached ESD Test Circuit). Latch-Up testing has shown that this device withstands a current of ± 250 mA.

Table 1 Reliability Evaluation Test Results

MAX2740ECM

TEST ITEM	TEST CONDITION	FAILURE IDENTIFICATION	PACKAGE	SAMPLE SIZE	NUMBER OF FAILURES
Static Life Test	: (Note 1)				
	Ta = 150°C Biased Time = 192 hrs.	DC Parameters & functionality		45	0
Moisture Testir	ng (Note 2)				
Pressure Pot	Ta = 121°C P = 15 psi. RH= 100% Time = 168hrs.	DC Parameters & functionality	TQFP	77	0
85/85	Ta = 85°C RH = 85% Biased Time = 1000hrs.	DC Parameters & functionality		77	0
Mechanical Str	ess (Note 2)				
Temperature Cycle	-65°C/150°C 1000 Cycles Method 1010	DC Parameters & functionality		77	0

Note 1: Life Test Data may represent plastic DIP qualification lots. Note 2: Generic Package/Process data

Attachment #1

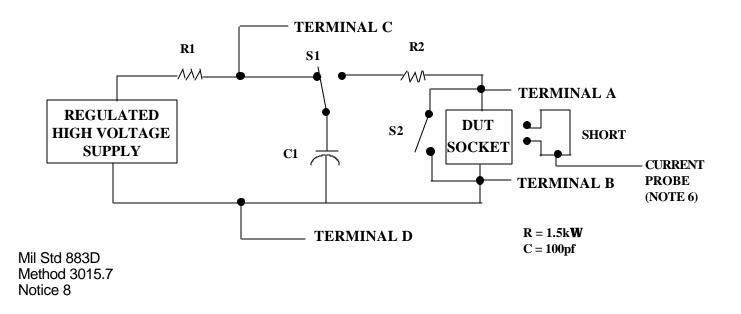
	Terminal A (Each pin individually connected to terminal A with the other floating)	Terminal B (The common combination of all like-named pins connected to terminal B)
1.	All pins except V _{PS1} <u>3/</u>	All V_{PS1} pins
2.	All input and output pins	All other input-output pins

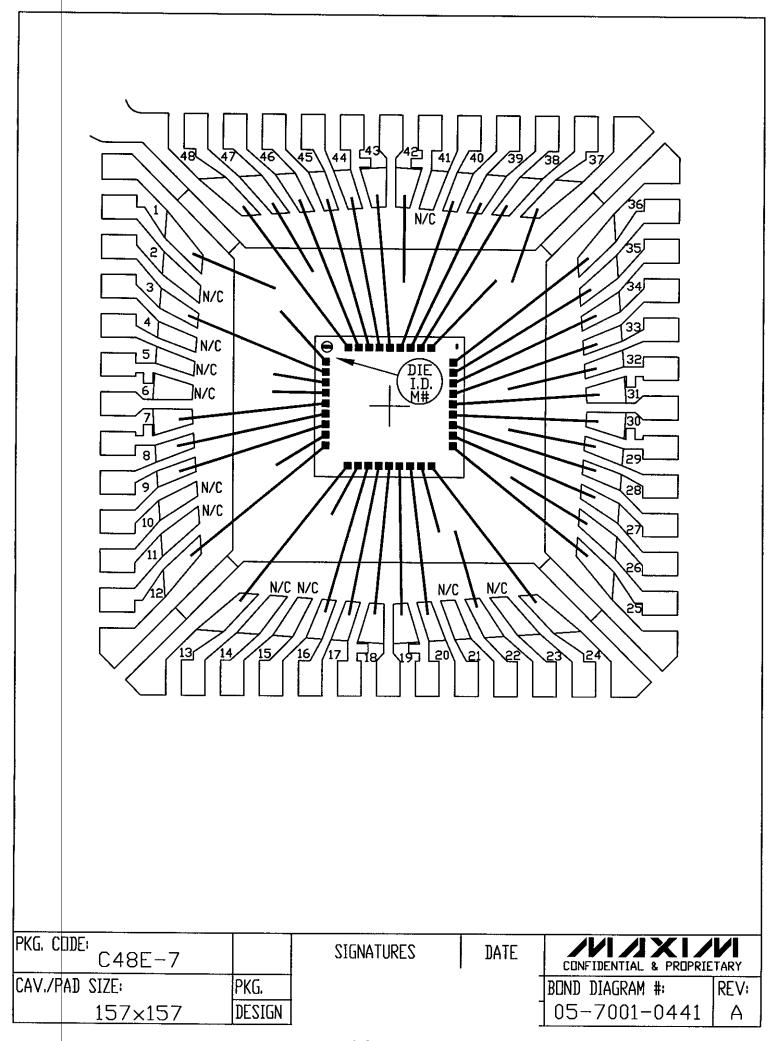
TABLE II. Pin combination to be tested. 1/2/

- 1/ Table II is restated in narrative form in 3.4 below.
- $\overline{2/}$ No connects are not to be tested.
- $\overline{3/}$ Repeat pin combination I for each named Power supply and for ground

(e.g., where V_{PS1} is V_{DD} , V_{CC} , V_{SS} , V_{BB} , GND, + V_{S} , - V_{S} , V_{REF} , etc).

- 3.4 <u>Pin combinations to be tested.</u>
 - a. Each pin individually connected to terminal A with respect to the device ground pin(s) connected to terminal B. All pins except the one being tested and the ground pin(s) shall be open.
 - b. Each pin individually connected to terminal A with respect to each different set of a combination of all named power supply pins (e.g., V_{SS1}, or V_{SS2} or V_{SS3} or V_{CC1}, or V_{CC2}) connected to terminal B. All pins except the one being tested and the power supply pin or set of pins shall be open.
 - c. Each input and each output individually connected to terminal A with respect to a combination of all the other input and output pins connected to terminal B. All pins except the input or output pin being tested and the combination of all the other input and output pins shall be open.





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